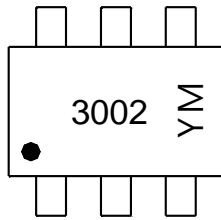


**Marking Information**



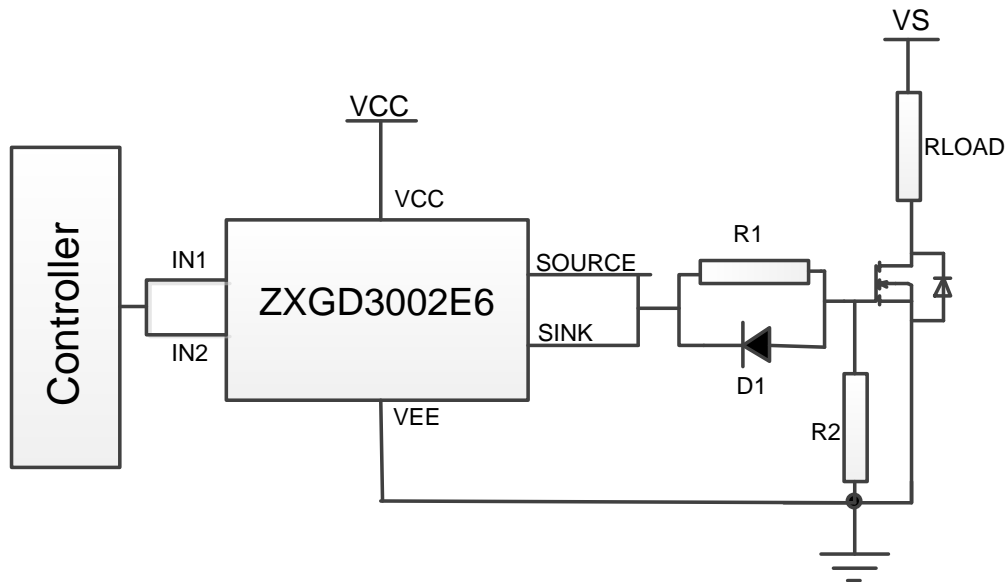
3002 = Product Type Marking Code  
 YM = Date Code Marking  
 Y or  $\bar{Y}$  = Year (ex: I = 2021)  
 M or  $\bar{M}$  = Month (ex: 9 = September)

Date Code Key

Year	2010	...	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	X	...	I	J	K	L	M	N	O	P	R	S

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

**Typical Application Circuit**



R1, D1 combination can be used for variable turn on and turn off times.

**Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Supply Voltage	V <sub>CC</sub>	20	V
Input Voltage	V <sub>IN</sub>	20	V
Output Difference Voltage (Source – Sink)	ΔV <sub>(source-sink)</sub>	±7	V
Peak Pulsed Output Current (Source & Sink)	I <sub>OM</sub>	±9	A
Peak Pulsed Input current	I <sub>IN1</sub> , I <sub>IN2</sub>	±1	A

**Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Notes 5 & 6)	P <sub>D</sub>	1.1	W
Linear Derating Factor		8.8	mW/°C
Thermal Resistance, Junction to Ambient (Notes 5 & 6)	R <sub>θJA</sub>	113	°C/W
Thermal Resistance, Junction to Lead (Note 7)	R <sub>θJL</sub>	105	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

**ESD Ratings** (Note 8)

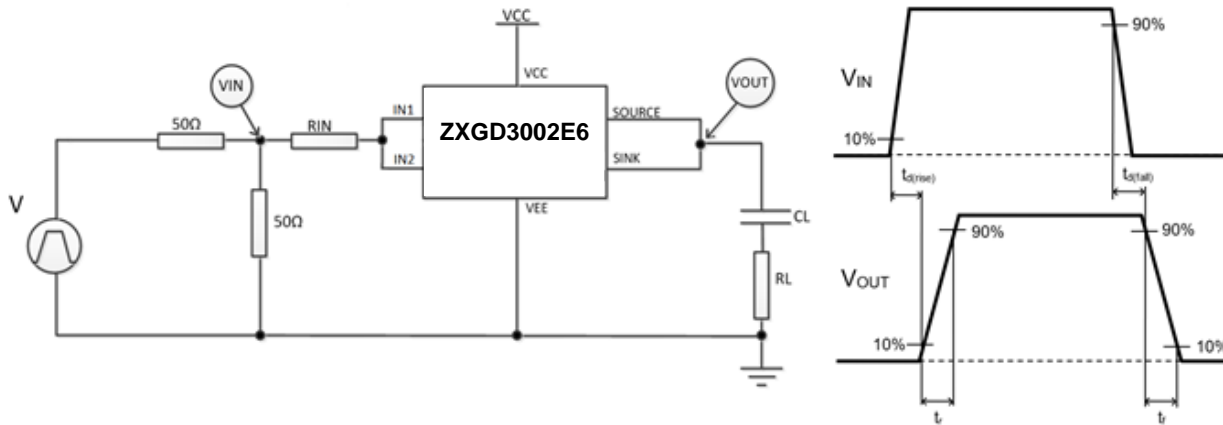
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C
Electrostatic Discharge – Charged Device Model	ESD CDM	1000	V	IV

- Notes:
5. For a device mounted on 25mm × 25mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions while operating in a steady-state. The heatsink is split in half with the pin 1 (V<sub>CC</sub>) and pin 3 (V<sub>EE</sub>) connected separately to each half.
  6. For device with two active die running at equal power.
  7. Thermal resistance from junction to solder-point at the end of each lead on pin 1 (V<sub>CC</sub>) and pin 3 (V<sub>EE</sub>).
  8. Refer to JEDEC specification JESD22-A114, JESD22-A115, and JESD22-C101.

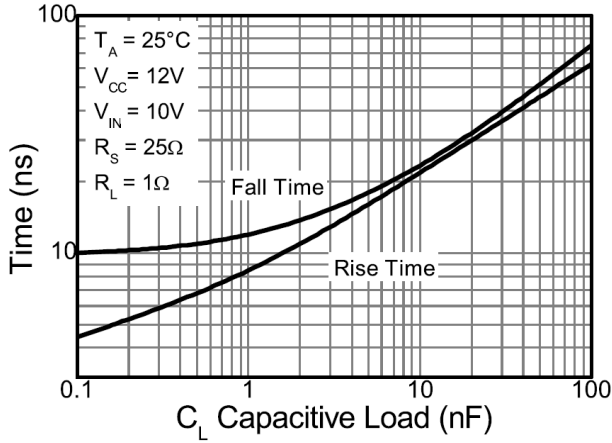
**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Output Voltage, High	V <sub>OUT(hi)</sub>	—	V <sub>CC</sub> - 0.4	—	V	I <sub>SOURCE</sub> = 1μA
Output Voltage, Low	V <sub>OUT(low)</sub>	—	V <sub>EE</sub> + 0.4	—	V	I <sub>SINK</sub> = 1μA
Source Output Leakage Current	I <sub>L(SOURCE)</sub>	—	—	1	μA	V <sub>CC</sub> = 20V, V <sub>IN1</sub> = V <sub>IN2</sub> = 0V
Sink Output Leakage Current	I <sub>L(SINK)</sub>	—	—	1	μA	V <sub>CC</sub> = 20V, V <sub>IN1</sub> = V <sub>IN2</sub> = V <sub>CC</sub>
Quiescent Current	I <sub>Q</sub>	—	—	50	nA	V <sub>CC</sub> = 16V, V <sub>IN1</sub> = V <sub>IN2</sub> = 0V
Peak Pulsed Source Output Current	I <sub>(SOURCE)M</sub>	1.6	2.2	—	A	I <sub>IN1</sub> + I <sub>IN2</sub> = 10mA
Peak Pulsed Sink Output Current	I <sub>(SINK)M</sub>	1.4	2	—	A	I <sub>IN1</sub> + I <sub>IN2</sub> = -10mA
Peak Pulsed Source Output Current	I <sub>(SOURCE)M</sub>	—	9	—	A	I <sub>IN1</sub> + I <sub>IN2</sub> = 1A
Peak Pulsed Sink Output Current	I <sub>(SINK)M</sub>	—	9	—	A	I <sub>IN1</sub> + I <sub>IN2</sub> = -1A
Gate Driver Switching Times	t <sub>D(RISE)</sub>	—	1.25	—	ns	V <sub>CC</sub> = 12V, V <sub>EE</sub> = 0V, V <sub>IN</sub> = 0 to 10V, C <sub>L</sub> = 1nF, R <sub>L</sub> = 1Ω, R <sub>IN</sub> = 25Ω
	t <sub>r</sub>		8.3			
	t <sub>D(FALL)</sub>		1.6			
	t <sub>f</sub>		10.8			
Gate Driver Switching Times	t <sub>D(RISE)</sub>	—	3.6	—	ns	V <sub>CC</sub> = 12V, V <sub>EE</sub> = 0V, V <sub>IN</sub> = 0 to 10V, C <sub>L</sub> = 1nF, R <sub>L</sub> = 1Ω, R <sub>IN</sub> = 1kΩ
	t <sub>r</sub>		105			
	t <sub>D(FALL)</sub>		6.9			
	t <sub>f</sub>		115			

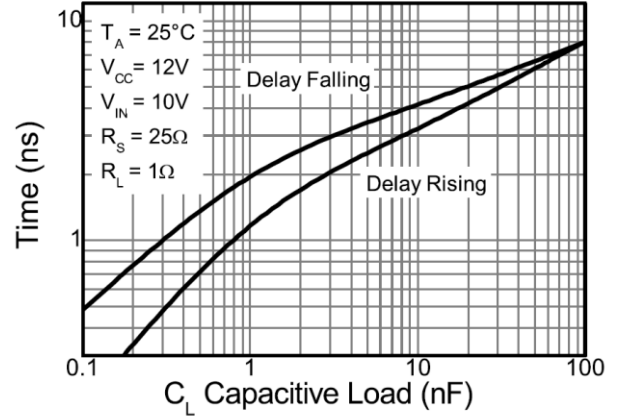
**Switching Test Circuit and Timing Diagram**



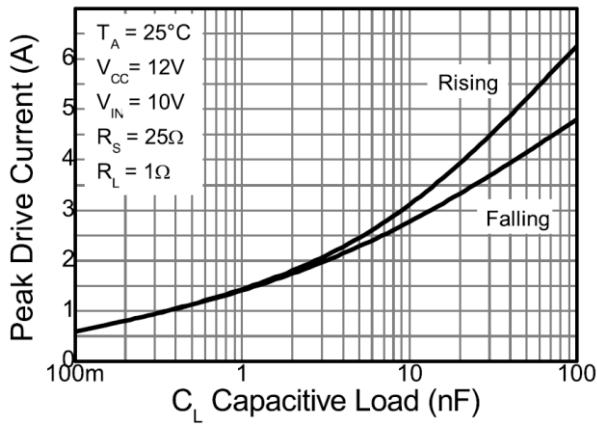
**Typical Switching Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



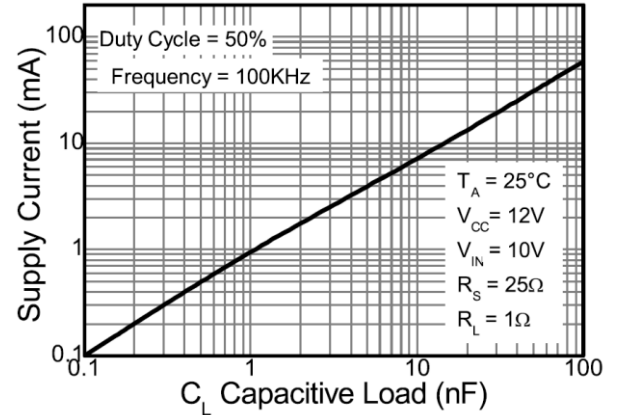
**Rise and Fall Time**



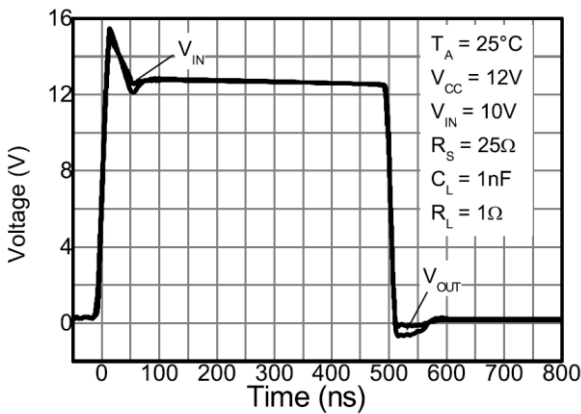
**Propagation Delay**



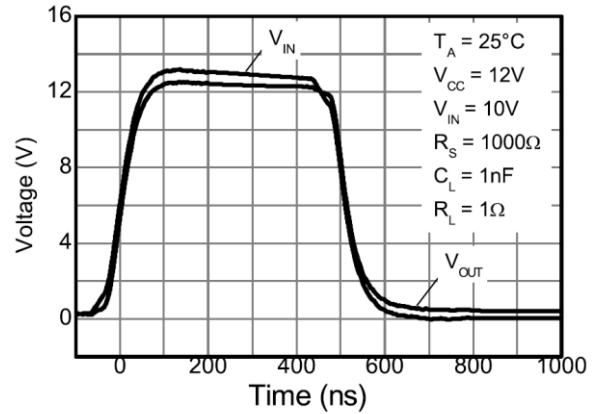
**Peak Drive Current**



**Supply Current**

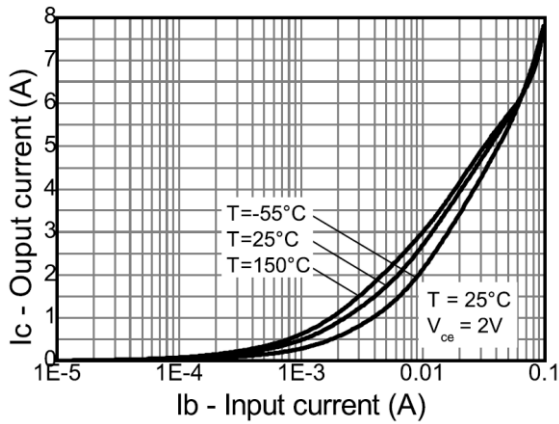


**Switching Speed**

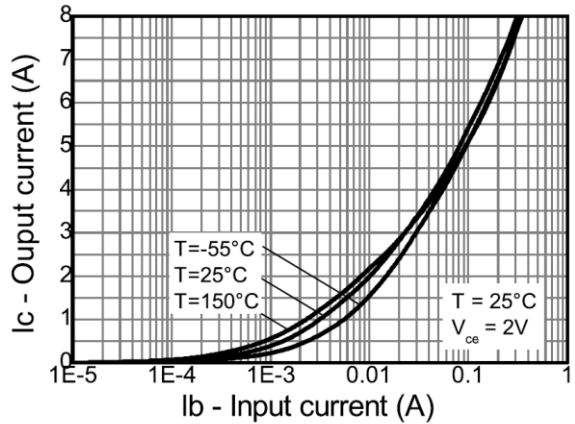


**Switching Speed**

**Typical Switching Characteristics** (Continued) (@T<sub>A</sub> = +25°C, unless otherwise specified.)



**Source Current Vs Input Current**

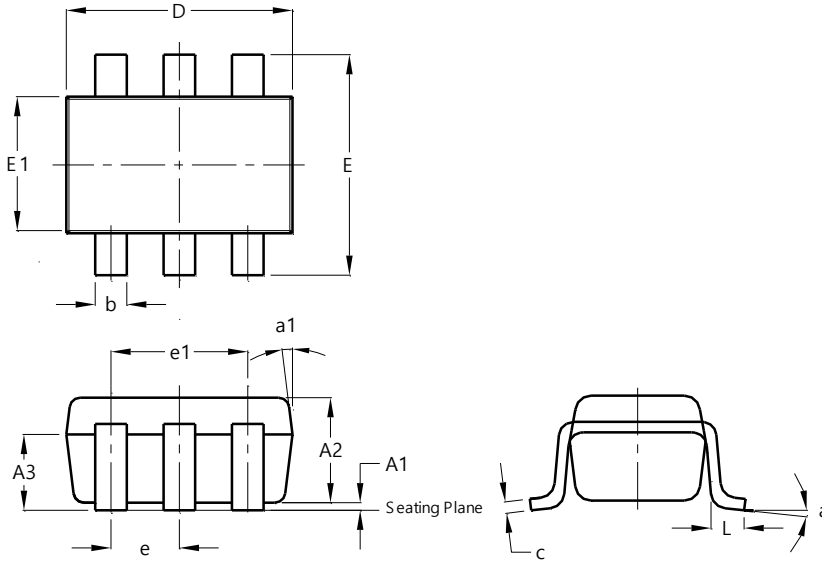


**Sink Current Vs Input Current**

**Package Outline Dimensions**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT26**

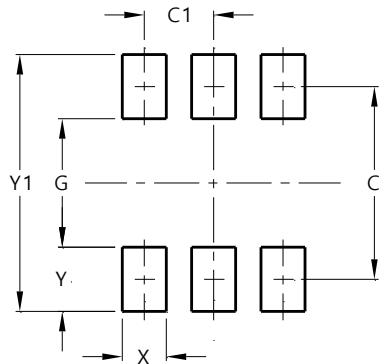


SOT26			
Dim	Min	Max	Typ
A1	0.013	0.10	0.05
A2	1.00	1.30	1.10
A3	0.70	0.80	0.75
b	0.35	0.50	0.38
c	0.10	0.20	0.15
D	2.90	3.10	3.00
e	-	-	0.95
e1	-	-	1.90
E	2.70	3.00	2.80
E1	1.50	1.70	1.60
L	0.35	0.55	0.40
a	-	-	8°
a1	-	-	7°
All Dimensions in mm			

**Suggested Pad Layout**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT26**



Dimensions	Value (in mm)
C	2.40
C1	0.95
G	1.60
X	0.55
Y	0.80
Y1	3.20

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